

An In-Depth Description of the Radiation Data Package for the QLS1046-Space Edge Processing Module

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Agenda

Introduction

DDR4 SEE Radiation Testing

Focus on QLS1046-Space

TID Verification

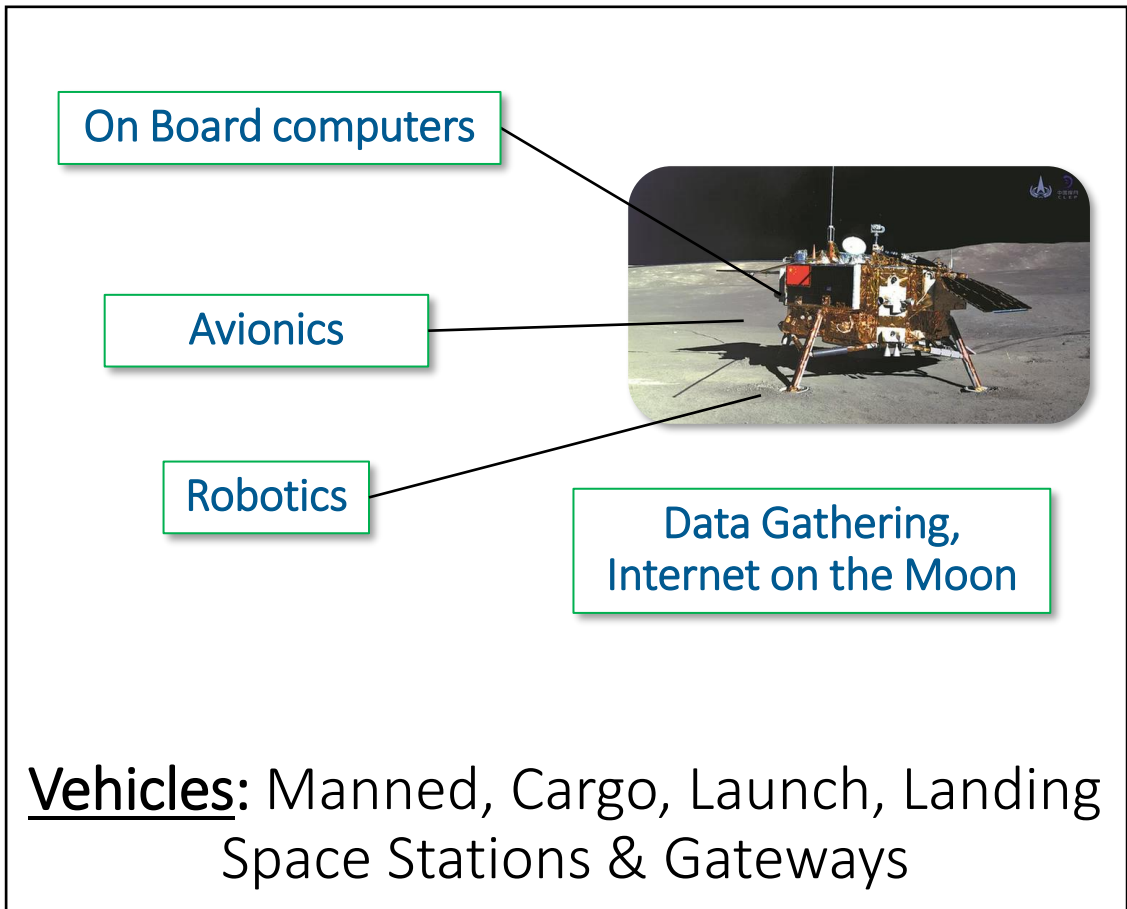
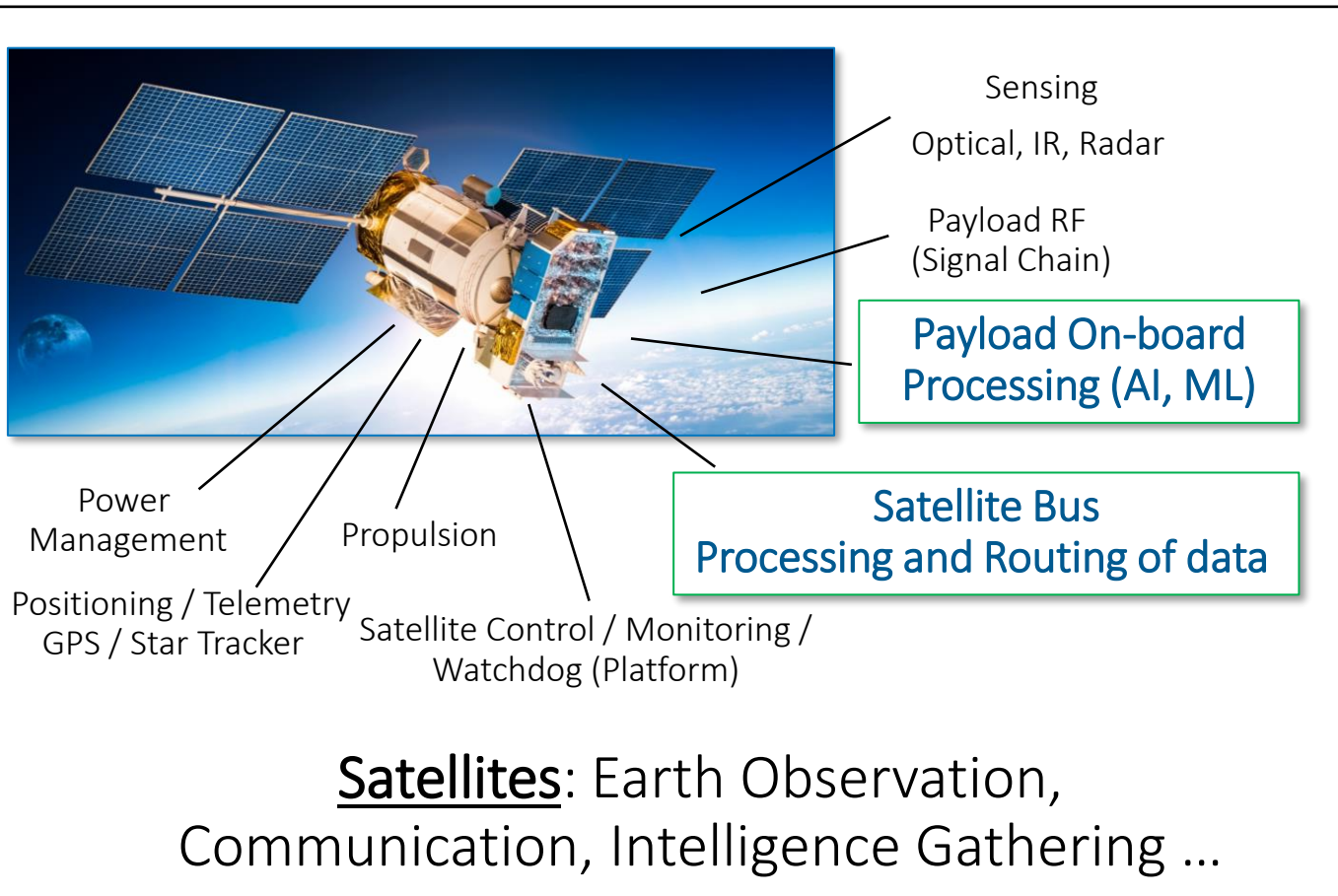
Radiation Testing Strategy

Conclusion

LS1046 SEE Radiation Testing

Teledyne e2v Data Processing Solutions

Addressable Projects & Target Applications in Space



Legenda : Addressable with Teledyne e2v Data Processing Solutions

High Level Processing Roadmap

R&D phases engaged to anticipate Next Gen Space computing needs

Shipping Now

Quad ARM® Cortex®-A72

15mm x 20mm x 1.92mm

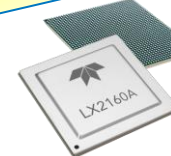


LS1046-Space DDR4T04G72M



QLS1046-Space

16x ARM® Cortex®-A72



LX2160-Space

Pin - Pin Compatibility 4GB & 8GB



DDR4 8GB

Objective : Serve Space Projects from 2024 onwards

Objective : Serve Space Projects Today

Mass Production

Single/Dual Core PowerArchitecture®



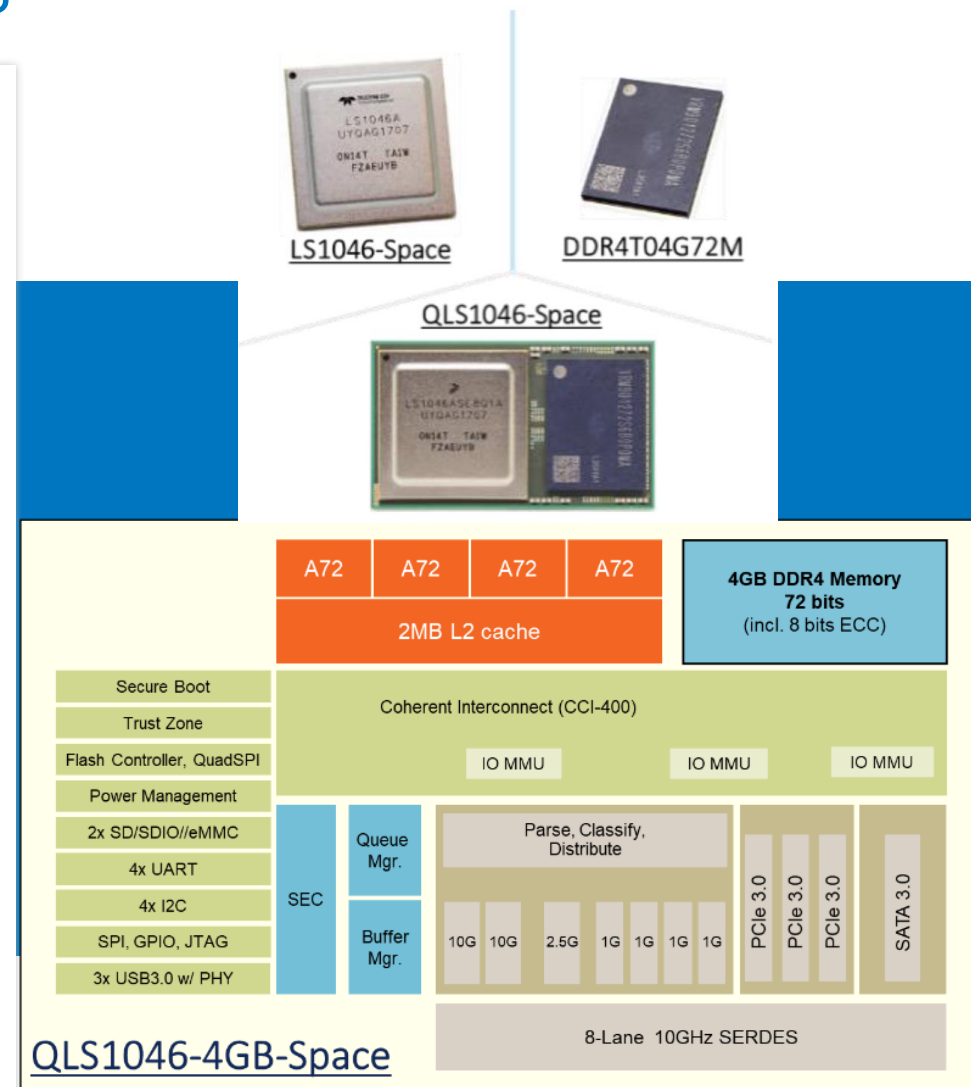
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PC8548

Serving Space Compute Intensive Market, QML-Y & NASA Grades

QLS1046-Space for Edge Computing

- ❖ Combination of LS1046-Space & DDR4T04G72 memory
- ❖ Heavy computing capabilities in ultra-compact design:
 - ❖ Quad-core 64-bit Arm® Cortex A72: Up to 30kDMIPS with NEON vector processing units (56GFLOPs)
 - ❖ Integrated 4GB x72bit DDR4 memory up to 2.4GT/s rate
 - ❖ 2MB total L2 cache, 1-10GbE, PCIe 3.0, UARTs, SPI, I²C, ...
 - ❖ Highly compact (44x26mm) and power efficient
- ❖ Radiation tolerant and Space qualified (NASA EEE-INST-002 - Section M4 – PEMs & ECSS-Q-ST-60-13C)



Teledyne e2v Compute Intensive Rad Tol solutions

Teledyne e2v Value Proposal

- Supplier of Advanced Radiation Tolerant Space Compute Intensive solutions
 - Bringing **existing COTS solutions** to **Space environments**
 - *Characterizations, Space Screening, Qualifications*
 - *Radiation Characterizations & Mitigations recommendations*
- Fully characterized, tested & qualified Space Compute Intensive solutions
 - Highest grade Characterizations, Testing & Qualifications – From Long lasting partnership with NXP
 - *Access to same platforms (test vectors, burn in platforms), same testers*
 - *Leading to highest quality testings and same test coverage*
 - Fully Tested and characterized in Radiation (TID, SEE Heavy Ions, Protons & mitigations)

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Teledyne e2v's Strategy for Radiations

- ❖ “Radiation Tolerant (RadTol)” Teledyne e2v’s definition:
 - ❖ No damage due to radiations
 - ❖ Can be subject to SEU (upsets) or SEFI (functional interrupts)
- ❖ SEE (Single Event Effects)
 - ❖ SEL immunity verification
 - ❖ SEU / SEFI characterization
- ❖ TID testing
 - ❖ Verifies lifetime in Space
- ❖ Mitigations techniques

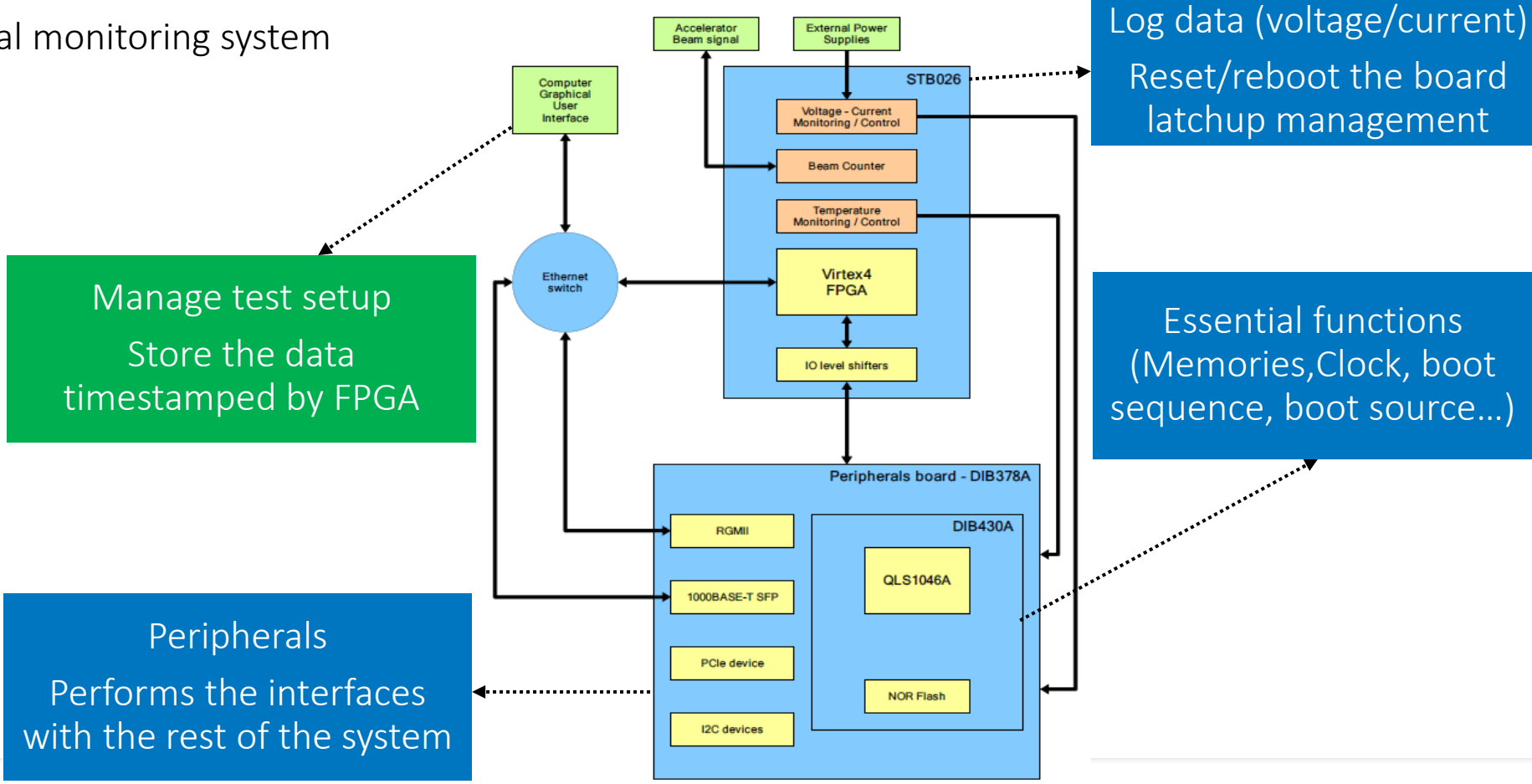
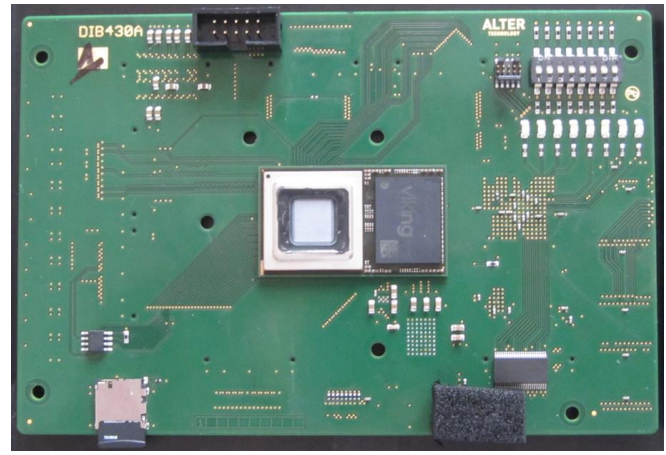


- ❖ For QLS1046-Space: Teledyne e2v performed tests of LS1046 processor and DDR4 one at a time

Teledyne e2v's Strategy for Radiations

- ❖ Based on specifically designed test HW and SW:
 - ❖ Permits to select the right testing configuration and relevant peripherals
 - ❖ Allows to monitor or control currents/voltage/temperature
 - ❖ Simplifies interface with general monitoring system
 - ❖ ...

Example of a QLS1046-Space test setup



LS1046 SEE Radiation Testing

SEL Results

- ❖ 3 devices tested
- ❖ At max temperature (125°C) & max operating voltage
- ❖ Fluence of $1e7$ ions/cm²
- ❖ No SEL detected up to 62 MeV/mg/cm²



Test performed at RADEF facilities
Effective LET at surface

16.3 MeV/n cocktail in air			
Ion	Range microns	LET at surface MeV/(mg/cm ²)	LET in air and through 75μ of Silicon MeV/(mg/cm ²)
17O6+	481	1.52	1.8
20Ne7+	360	2.3	2.6
40Ar14+	264	7.2	8
57FE20+	214	13.3	16
89Kr29+	185	24.5	32
126Xe44+	157	48.5	62.5

LS1046 SEE Radiation Testing

SEFI/SEU Characterization under Heavy-Ions

❖ FPGA monitors CPU activity and takes actions when SEFI : Algorithm to classify the SEFI event by recovering method

Table 6: SEFI rates on 3 orbits for 3 solar conditions, in n° of SEFI per day

	GEO	ISS	Proba 2
Solar min	$1.07 \cdot 10^{-3}$	$1.55 \cdot 10^{-4}$	$3.67 \cdot 10^{-4}$
Worst day	7.63	$2.70 \cdot 10^{-3}$	1.69
Worst 5min	28.5	$9.62 \cdot 10^{-3}$	6.31

❖ **Takeways:**

- ❖ No power cycle required to cure SEFI
- ❖ 1 SEFI per 1000 days in GEO normal conditions

- ❖ SEU events characterized on L2 cache & On-chip RAM
- ❖ Peripherals were also characterized SEU/SEFI

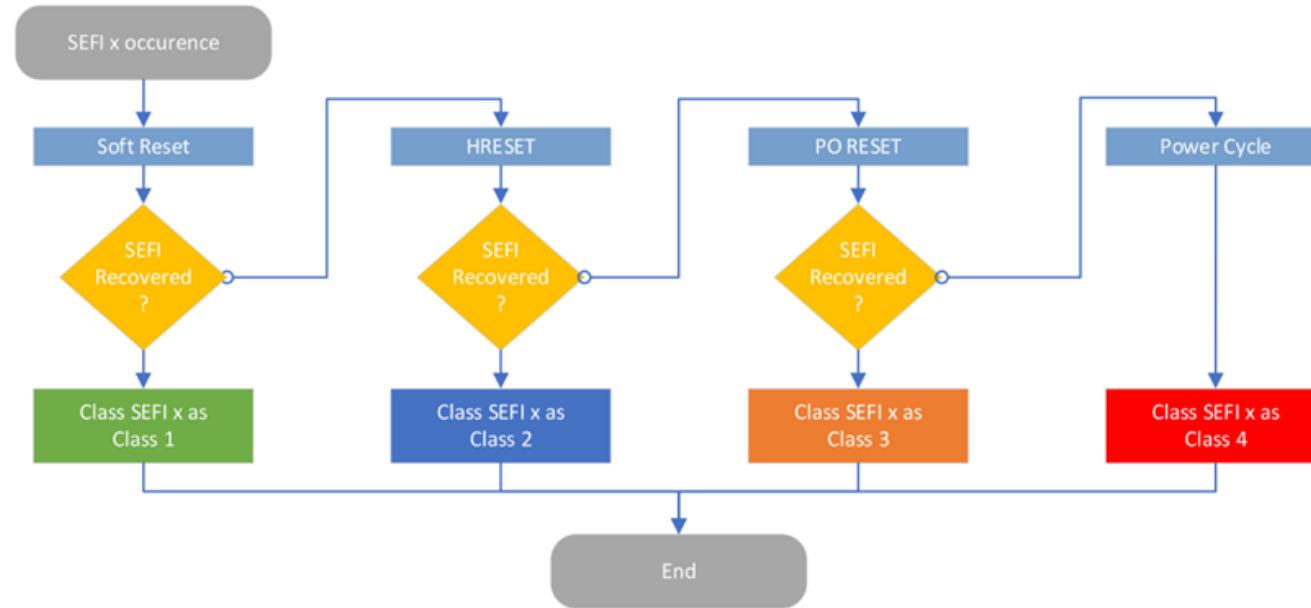


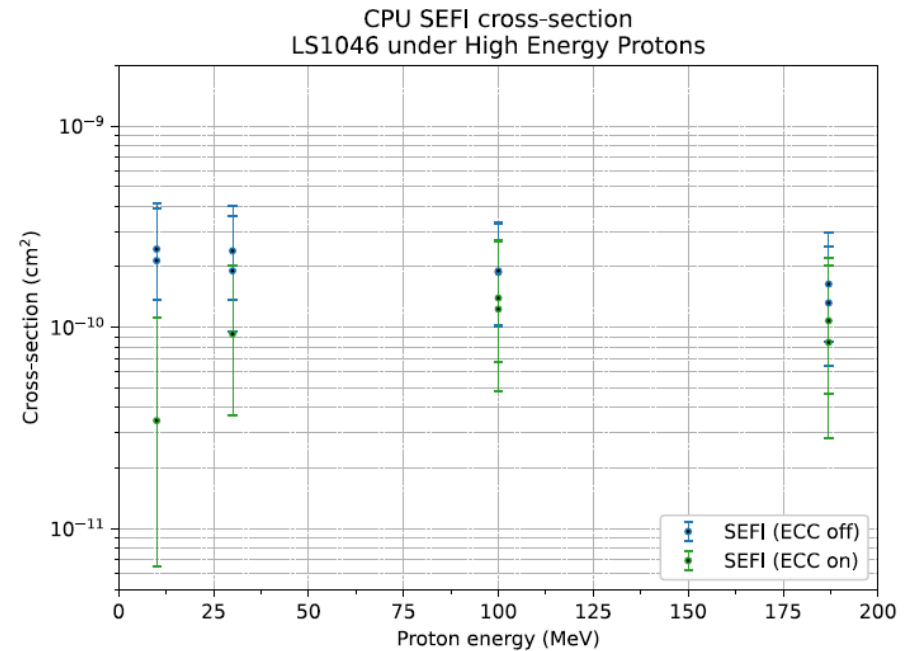
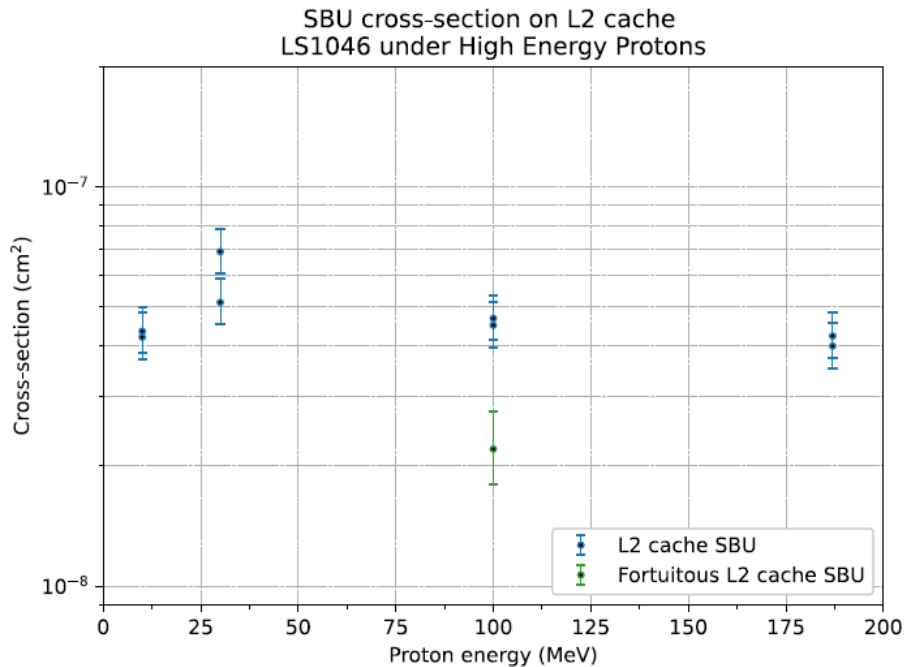
Table 9: SEU rates on 3 orbits for 3 solar conditions, in n° of SEU device per day

	GEO	ISS	Proba 2
Solar min	$1.96 \cdot 10^{-1}$	$2.68 \cdot 10^{-2}$	$6.61 \cdot 10^{-2}$
Worst day	$1.56 \cdot 10^2$	$2.06 \cdot 10^{-1}$	$3.49 \cdot 10^1$
Worst 5min	$5.80 \cdot 10^2$	$6.94 \cdot 10^{-1}$	$1.30 \cdot 10^2$

LS1046 SEE Radiation Testing

Protons Results

- ❖ 2 samples tested
- ❖ Proton beam up to 190MeV
- ❖ On-chip RAM and L2 cache were tested



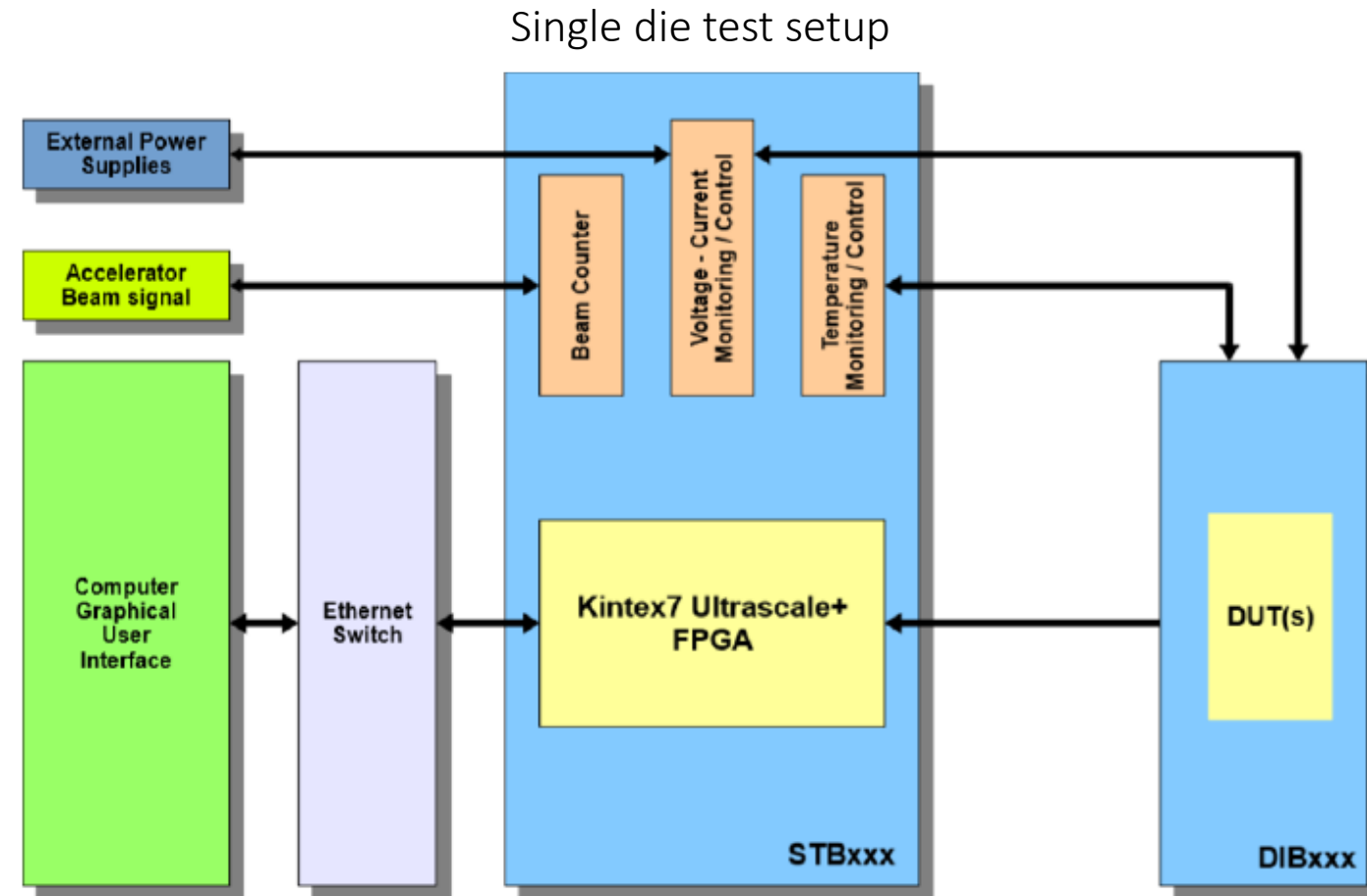
- ❖ ECC protection on L2 cache corrects SBU !

DDR4 SEE Radiation Testing

Test Setup

- ❖ DDR4 tested in 2 ways :
 - ❖ With QLS1046 test setup
 - ❖ Single die setup for in-depth testing

- ❖ Single die setup:
 - ❖ Connects a SODIMM daughter board (DUT)
 - ❖ Memory is interfaced directly with a FPGA
 - ❖ Gets full-visibility on the SEE
 - ❖ Power supplies monitored to detect SEL



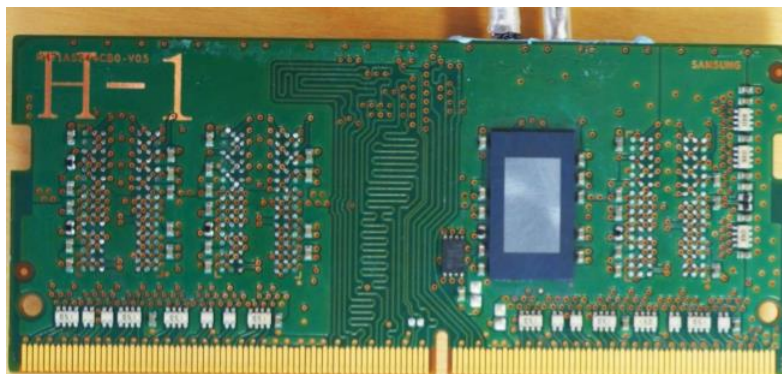
DDR4 SEE Radiation Testing

SEL Results

- ❖ At 95°C operating temperature and max operating voltage
- ❖ Fluence up to $1e7$ ions/cm²
- ❖ No SEL detected up to 60 MeV/mg/cm²

Test performed at RADEF facilities

Effective LET at surface (based on part thinning)

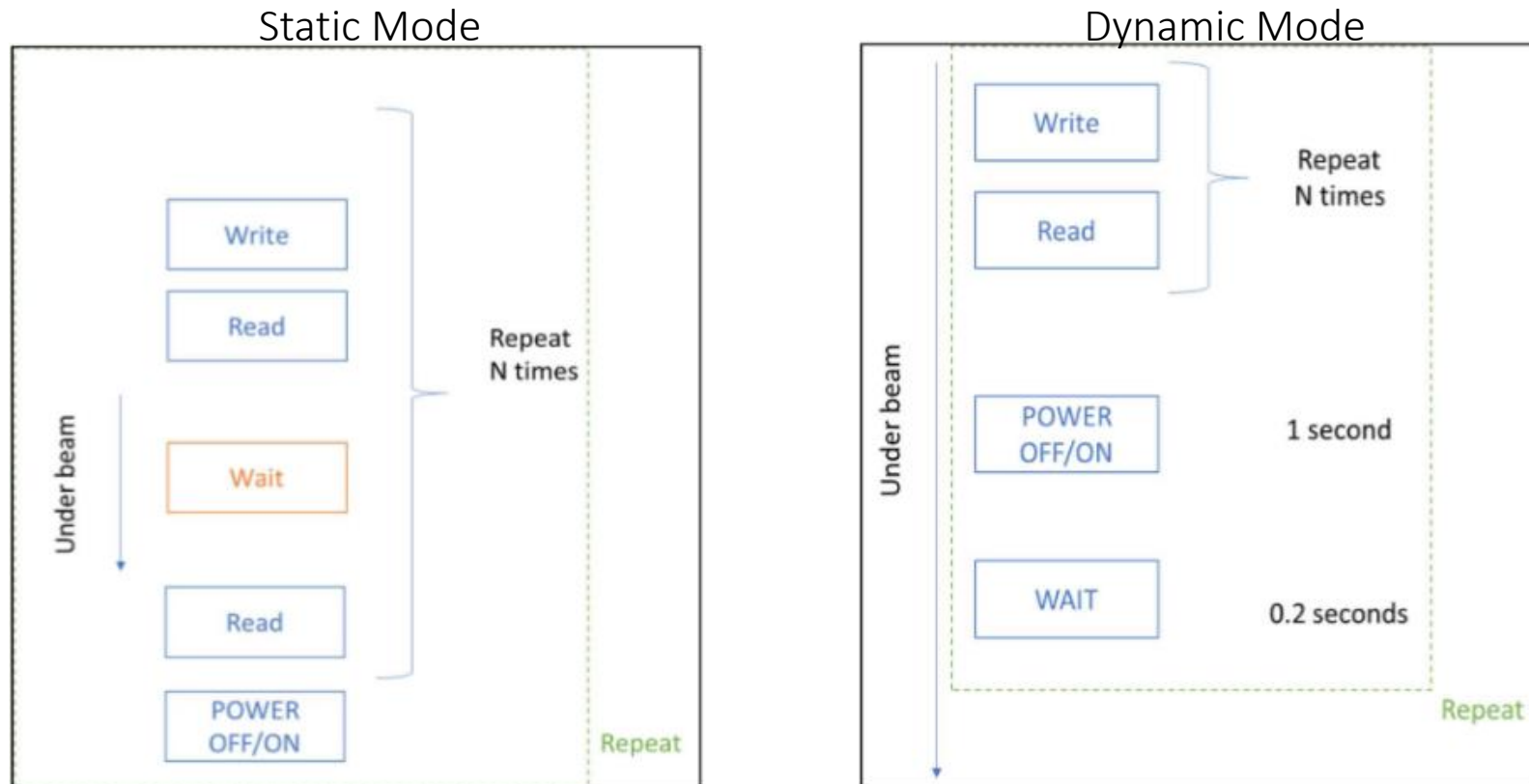


Ion	LET ^{SRIM} at surface [MeV.cm ² .mg ⁻¹]	Range [μm]	Beam energy [MeV]	Back irradiation LET Die Silicon thickness SRIM 2013	
				70μ	80μ
¹⁷ O ⁶⁺	1.52	481	284	1.54	1.56
²⁰ Ne ⁷⁺	2.3	360	328	2.6	2.65
⁴⁰ Ar ¹⁴⁺	7.2	264	657	8.19	8.38
⁵⁷ Fe ²⁰⁺	13.3	214	941	15.69	16.17
⁸³ Kr ²⁹⁺	24.5	185	1358	30.06	31.12
¹²⁶ Xe ⁴⁴⁺	48.5	157	2059	60.88	63.07

DDR4 SEE Radiation Testing

SEFI/SEU Characterization under Heavy-Ions

- ❖ Two ways of testing SEU:
 - ❖ Static: Memory not exercised under the beam
 - ❖ Dynamic: Memory is exercised under the beam



DDR4 SEE Radiation Testing

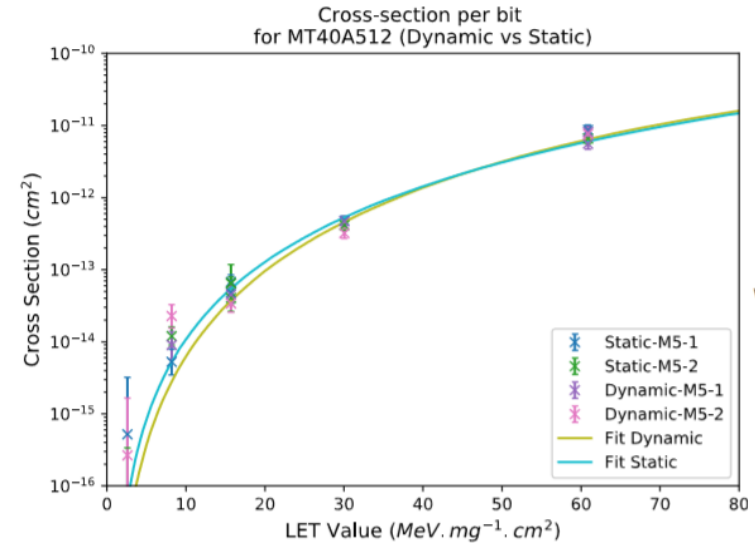
SEFI/SEU Characterization under Heavy-Ions

❖ SEU results:

- ❖ Similar results between static and dynamic mode

❖ SEFI characterized and classified :

- ❖ DDR4 reset sufficient to clear SEFIs up to 25 MeV/(mg/cm²)

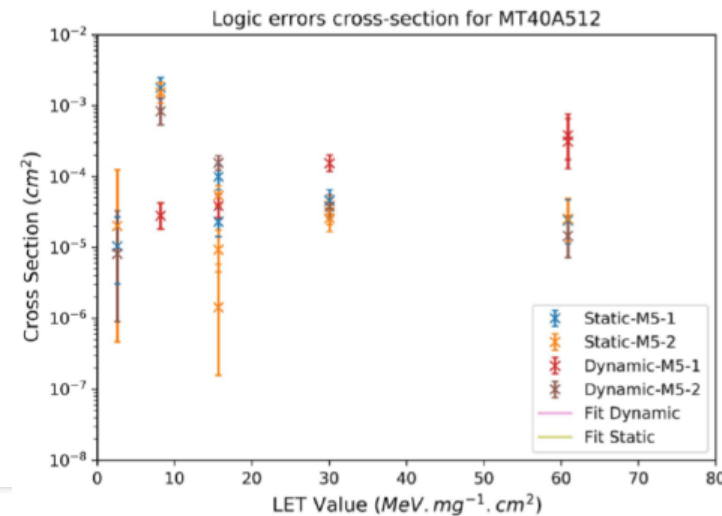


Weibull parameters (Static mode)

Parameter	Value
A	1.14E-10
x ₀	0.5
S	3.43
W	141.29

Weibull parameters (Dynamic mode)

Parameter	Value
A	4.49E-11
x ₀	0.5
S	3.79
W	98.87

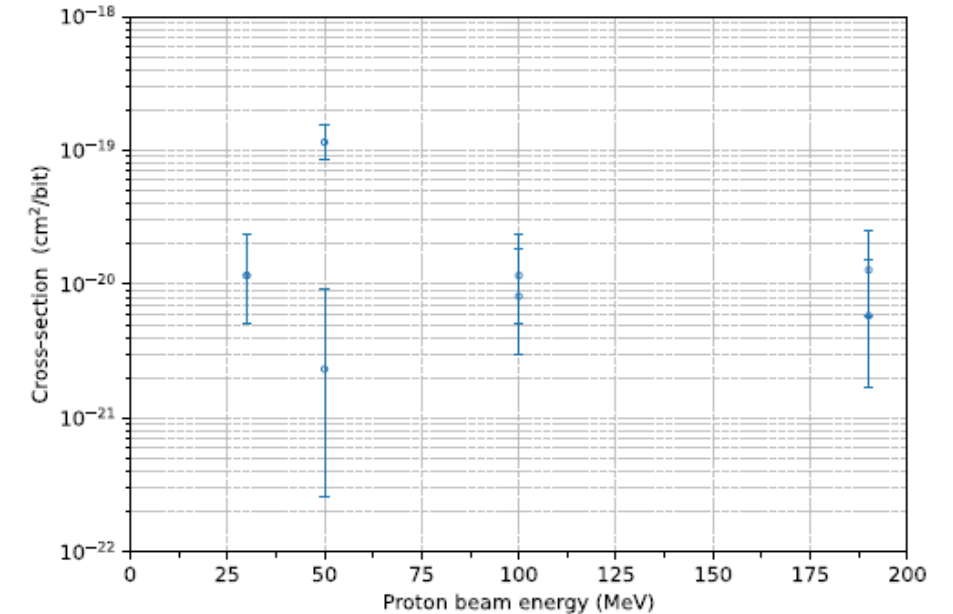


DDR4 SEE Radiation Testing

Protons Results

- ❖ 2 samples (tested in single die)
- ❖ Proton beam up to 190MeV

RUN	Proton energy (MeV)	Fluence (p+.cm ⁻²)	Dose (krad)	Duration (s)	BoardID	Bits	Upsets	Upset cross-section (cm ² /bit)	Row errors	Column errors
RUN001	100	1.00E+11	9.34	1477	6	8,589,934,592	7	8.15E-21	6770	692
RUN002	190	1.00E+11	6.00	1493	6	8,589,934,592	5	5.82E-21	5144	418
RUN006	190	1.00E+11	6.00	1418	7	8,589,934,592	11	1.28E-20	17505	448
RUN007	100	1.00E+11	9.34	1414	7	8,589,934,592	10	1.16E-20	12075	374
RUN010	50	1.00E+11	15.82	1498	7	8,589,934,592	99	1.15E-19	14595	287
RUN011	30	1.00E+11	23.63	1572	7	8,589,934,592	10	1.16E-20	10024	216
RUN012	30	1.00E+11	23.63	1429	6	8,589,934,592	10	1.16E-20	8148	392
RUN013	50	1.00E+11	15.82	1487	6	8,589,934,592	2	2.33E-21	8665	544



❖ Main takeaways:

- ❖ All upsets are SBU => corrected by ECC !
- ❖ Low-sensitivity at all energies: in the range of 1e-20 cm²/bit
- ❖ Logic errors (row and column) are mitigated by applying “reset” operation

TID verification

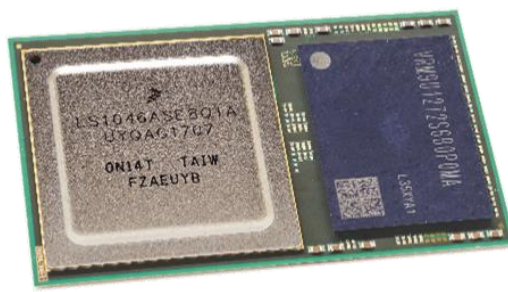
LS1046-Space & DDR4

- ❖ LS1046-Space
 - ❖ Dose up to 100 krad (Si)
 - ❖ 6 Samples biased ON using a dummy software
 - ❖ 6 Samples biased OFF (all pin connected to Ground)
 - ❖ Use of UltraFLEX equipment for electrical testing (Teledyne e2v industrial tester)

- ❖ DDR4T04G72
 - ❖ Dose up to 100 krad (Si)
 - ❖ 5 Samples biased ON
 - ❖ 5 Samples biased OFF (all pin connected to Ground)

- ❖ Successful results: LS1046-Space and DDR4T04G72 can sustain a dose of 100krad (Si)

Conclusion



- ❖ Quick recap:
 - ❖ Radiation testing strategy applied by Teledyne e2v on its edge processing devices
 - ❖ Presented the setups and main radiation results for QSL1046-Space:
 - ❖ LS1046-Space processor results,
 - ❖ DDR4T04G72 results,
- ❖ QLS1046-Space offers a good radiation performance with a comprehensive set of data
 - ❖ Detailed results available in radiation reports (available upon request)

Credits

- Teledyne e2v LS1046—Space project, on which QLS1046-Space is based, is supported by CNES (French Space Agency) through an ESA ARTES program



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QUESTIONS ?